Welcome to E-XFL.COM

Understanding Embedded - FPGAs (Field Programmable Gate Array)

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

Details	
Product Status	Obsolete
Number of LABs/CLBs	196
Number of Logic Elements/Cells	1960
Total RAM Bits	-
Number of I/O	171
Number of Gates	24000
Voltage - Supply	3V ~ 3.6V
Mounting Type	Surface Mount
Operating Temperature	0°C ~ 85°C (TJ)
Package / Case	208-BFQFP
Supplier Device Package	208-PQFP (28x28)
Purchase URL	https://www.e-xfl.com/product-detail/intel/epf6024aqc208-1

Functional Description

The FLEX 6000 OptiFLEX architecture consists of logic elements (LEs). Each LE includes a 4-input look-up table (LUT), which can implement any 4-input function, a register, and dedicated paths for carry and cascade chain functions. Because each LE contains a register, a design can be easily pipelined without consuming more LEs. The specified gate count for FLEX 6000 devices includes all LUTs and registers.

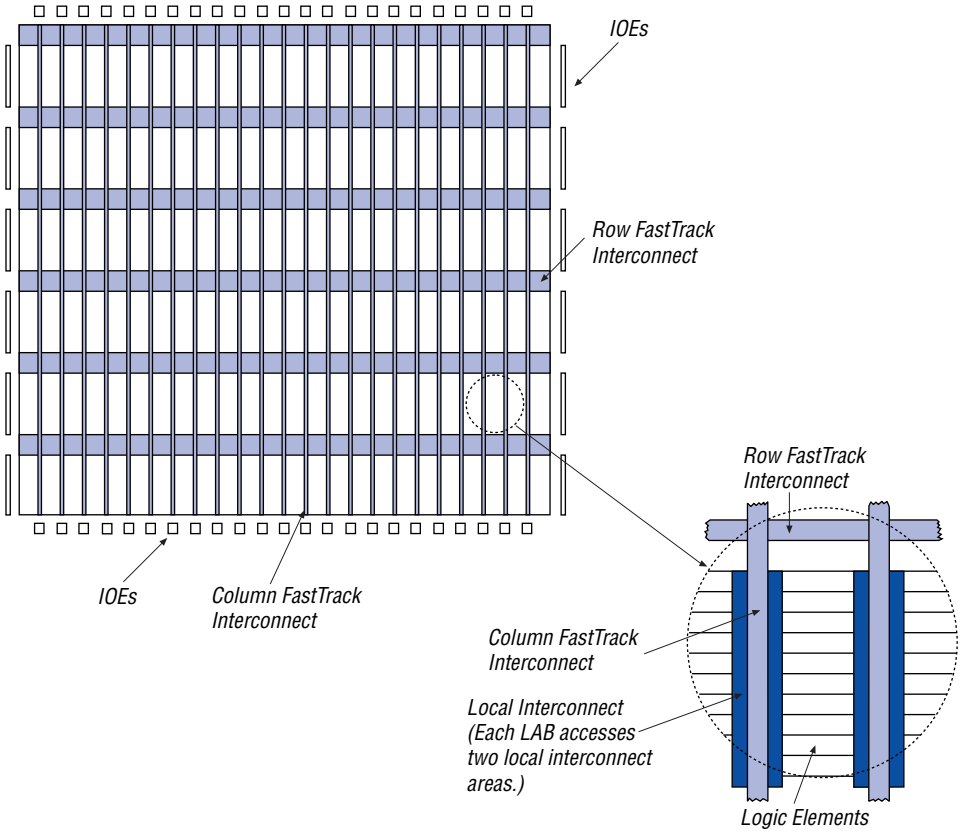
LEs are combined into groups called logic array blocks (LABs); each LAB contains 10 LEs. The Altera software automatically places related LEs into the same LAB, minimizing the number of required interconnects. Each LAB can implement a medium-sized block of logic, such as a counter or multiplexer.

Signal interconnections within FLEX 6000 devices—and to and from device pins—are provided via the routing structure of the FastTrack Interconnect. The routing structure is a series of fast, continuous row and column channels that run the entire length and width of the device. Any LE or pin can feed or be fed by any other LE or pin via the FastTrack Interconnect. See "FastTrack Interconnect" on page 17 of this data sheet for more information.

Each I/O pin is fed by an I/O element (IOE) located at the end of each row and column of the FastTrack Interconnect. Each IOE contains a bidirectional I/O buffer. Each IOE is placed next to an LAB, where it can be driven by the local interconnect of that LAB. This feature allows fast clock-to-output times of less than 8 ns when a pin is driven by any of the 10 LEs in the adjacent LAB. Also, any LE can drive any pin via the row and column interconnect. I/O pins can drive the LE registers via the row and column interconnect, providing setup times as low as 2 ns and hold times of 0 ns. IOEs provide a variety of features, such as JTAG BST support, slew-rate control, and tri-state buffers.

Figure 1 shows a block diagram of the FLEX 6000 OptiFLEX architecture. Each group of ten LEs is combined into an LAB, and the LABs are arranged into rows and columns. The LABs are interconnected by the FastTrack Interconnect. IOEs are located at the end of each FastTrack Interconnect row and column.

Figure 1. OptiFLEX Architecture Block Diagram

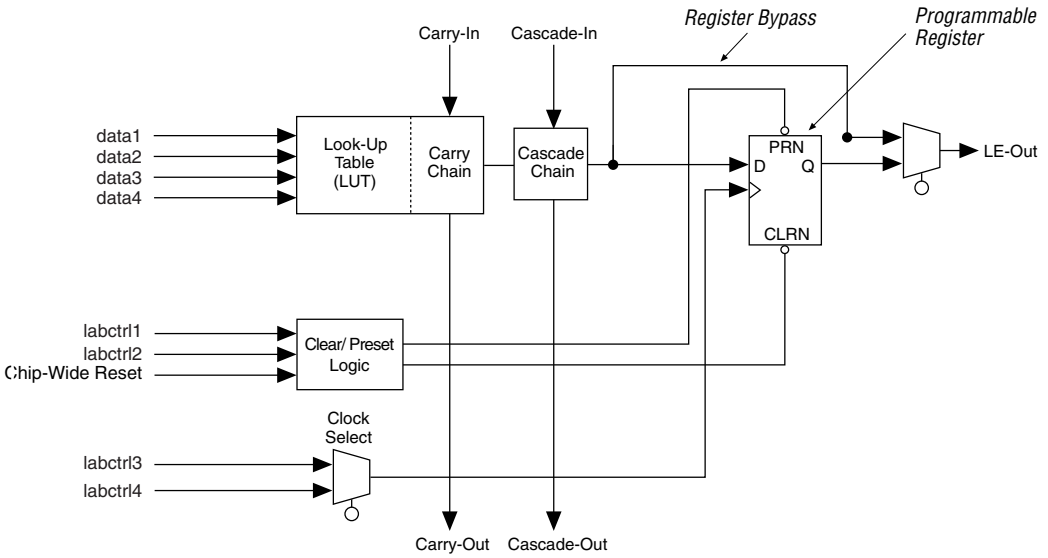


FLEX 6000 devices provide four dedicated, global inputs that drive the control inputs of the flipflops to ensure efficient distribution of high-speed, low-skew control signals. These inputs use dedicated routing channels that provide shorter delays and lower skews than the FastTrack Interconnect. These inputs can also be driven by internal logic, providing an ideal solution for a clock divider or an internally generated asynchronous clear signal that clears many registers in the device. The dedicated global routing structure is built into the device, eliminating the need to create a clock tree.

Logic Array Block

An LAB consists of ten LEs, their associated carry and cascade chains, the LAB control signals, and the LAB local interconnect. The LAB provides the coarse-grained structure of the FLEX 6000 architecture, and facilitates efficient routing with optimum device utilization and high performance.

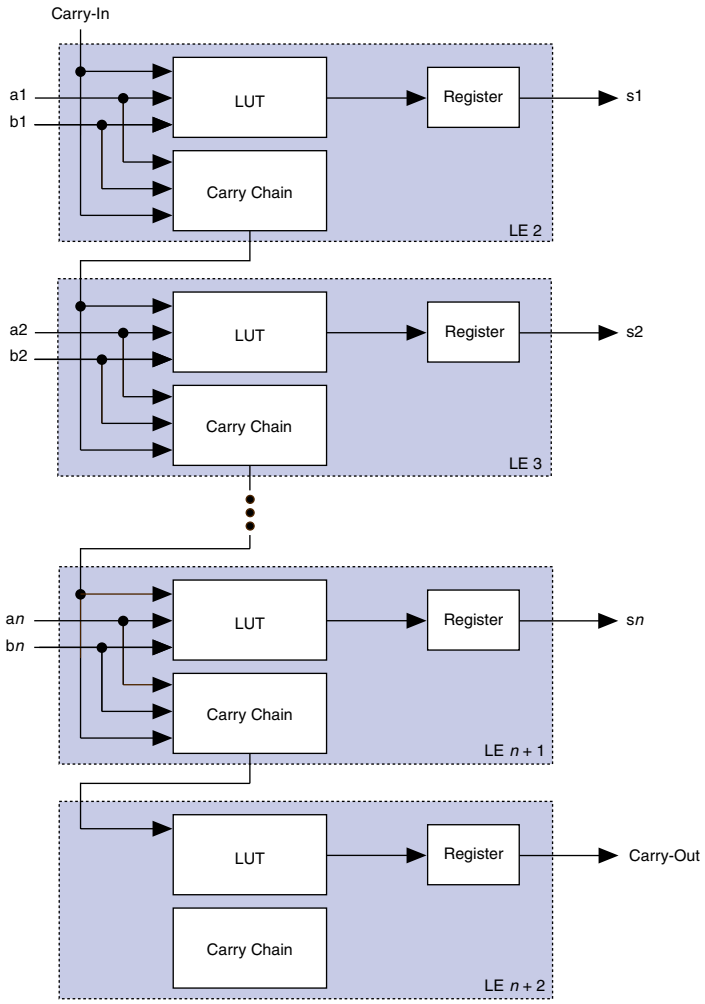
Figure 4. Logic Element



The programmable flipflop in the LE can be configured for D, T, JK, or SR operation. The clock and clear control signals on the flipflop can be driven by global signals, general-purpose I/O pins, or any internal logic. For combinatorial functions, the flipflop is bypassed and the output of the LUT drives the outputs of the LE. The LE output can drive both the local interconnect and the FastTrack Interconnect.

The FLEX 6000 architecture provides two types of dedicated high-speed data paths that connect adjacent LEs without using local interconnect paths: carry chains and cascade chains. A carry chain supports high-speed arithmetic functions such as counters and adders, while a cascade chain implements wide-input functions such as equivalent comparators with minimum delay. Carry and cascade chains connect LEs 2 through 10 in an LAB and all LABs in the same half of the row. Because extensive use of carry and cascade chains can reduce routing flexibility, these chains should be limited to speed-critical portions of a design.

Figure 5. Carry Chain Operation



Cascade Chain

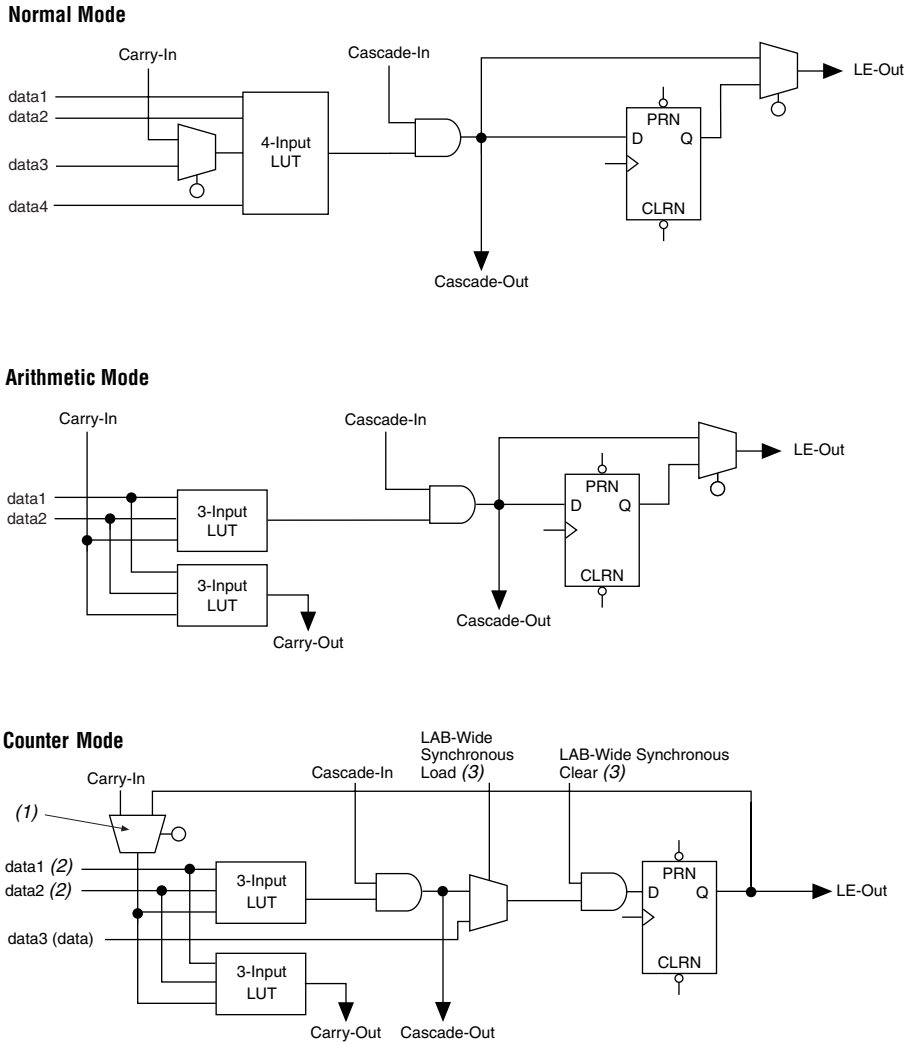
The cascade chain enables the FLEX 6000 architecture to implement very wide fan-in functions. Adjacent LUTs can be used to implement portions of the function in parallel; the cascade chain serially connects the intermediate values. The cascade chain can use a logical AND or logical OR gate (via De Morgan's inversion) to connect the outputs of adjacent LEs. Each additional LE provides four more inputs to the effective width of a function, with a delay as low as 0.5 ns per LE. Cascade chain logic can be created automatically by the Altera software during design processing, or manually by the designer during design entry. Parameterized functions such as LPM and DesignWare functions automatically take advantage of cascade chains for the appropriate functions.

A cascade chain implementing an AND gate can use the register in the last LE; a cascade chain implementing an OR gate cannot use this register because of the inversion required to implement the OR gate.

Because the first LE of an LAB can generate control signals for that LAB, the first LE in each LAB is not included in cascade chains. Moreover, cascade chains longer than nine bits are automatically implemented by linking several LABs together. For easier routing, a long cascade chain skips every other LAB in a row. A cascade chain longer than one LAB skips either from an even-numbered LAB to another even-numbered LAB, or from an odd-numbered LAB to another odd-numbered LAB. For example, the last LE of the first LAB in a row cascades to the second LE of the third LAB. The cascade chain does not cross the center of the row. For example, in an EPF6016 device, the cascade chain stops at the 11th LAB in a row and a new cascade chain begins at the 12th LAB.

Figure 6 shows how the cascade function can connect adjacent LEs to form functions with a wide fan-in. In this example, functions of 4*n* variables are implemented with *n* LEs. The cascade chain requires 3.4 ns to decode a 16-bit address.

Figure 7. LE Operating Modes



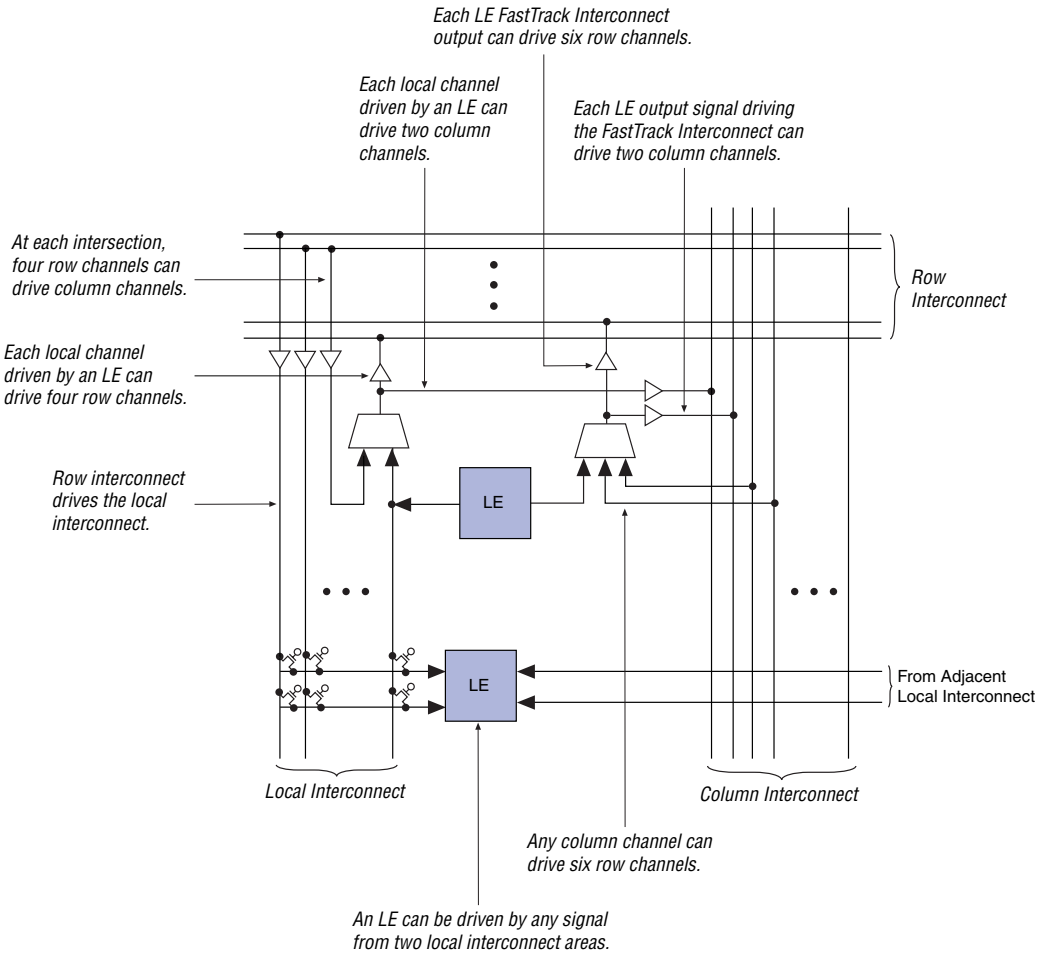
Notes:

(1) The register feedback multiplexer is available on LE 2 of each LAB.

(2) The `data1` and `data2` input signals can supply a clock enable, up or down control, or register feedback signals for all LEs other than the second LE in an LAB.

(3) The LAB-wide synchronous clear and LAB-wide synchronous load affect all registers in an LAB.

Figure 10. LAB Connections to Row & Column Interconnects



For improved routability, the row interconnect consists of full-length and half-length channels. The full-length channels connect to all LABs in a row; the half-length channels connect to the LABs in half of the row. In addition to providing a predictable, row-wide interconnect, this architecture provides increased routing resources. Two neighboring LABs can be connected using a half-length channel, which saves the other half of the channel for the other half of the row. One-third of the row channels are half-length channels.

I/O Elements

An IOE contains a bidirectional I/O buffer and a tri-state buffer. IOEs can be used as input, output, or bidirectional pins. An IOE receives its data signals from the adjacent local interconnect, which can be driven by a row or column interconnect (allowing any LE in the device to drive the IOE) or by an adjacent LE (allowing fast clock-to-output delays). A FastFLEX™ I/O pin is a row or column output pin that receives its data signals from the adjacent local interconnect driven by an adjacent LE. The IOE receives its output enable signal through the same path, allowing individual output enables for every pin and permitting emulation of open-drain buffers. The Altera Compiler uses programmable inversion to invert the data or output enable signals automatically where appropriate. Open-drain emulation is provided by driving the data input low and toggling the OE of each IOE. This emulation is possible because there is one OE per pin.

A chip-wide output enable feature allows the designer to disable all pins of the device by asserting one pin (DEV_OE). This feature is useful during board debugging or testing.

Figure 12 shows the IOE block diagram.

Figure 12. IOE Block Diagram

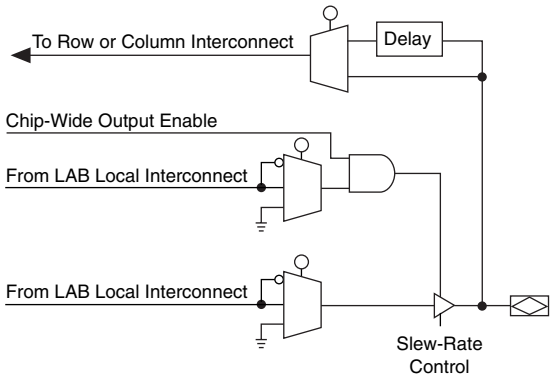
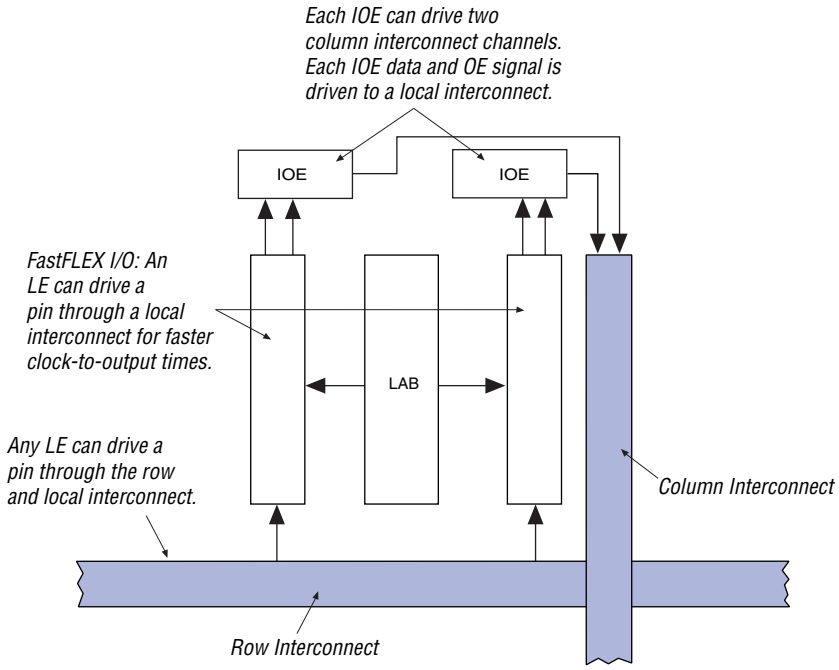


Figure 14. IOE Connection to Column Interconnect



SameFrame Pin-Outs

3.3-V FLEX 6000 devices support the SameFrame pin-out feature for FineLine BGA packages. The SameFrame pin-out feature is the arrangement of balls on FineLine BGA packages such that the lower-ball-count packages form a subset of the higher-ball-count packages. SameFrame pin-outs provide the flexibility to migrate not only from device to device within the same package, but also from one package to another. A given printed circuit board (PCB) layout can support multiple device density/package combinations. For example, a single board layout can support an EPF6016A device in a 100-pin FineLine BGA package or an EPF6024A device in a 256-pin FineLine BGA package.

The Altera software packages provide support to design PCBs with SameFrame pin-out devices. Devices can be defined for present and future use. The Altera software packages generate pin-outs describing how to lay out a board to take advantage of this migration (see Figure 15).

Figure 15. SameFrame Pin-Out Example

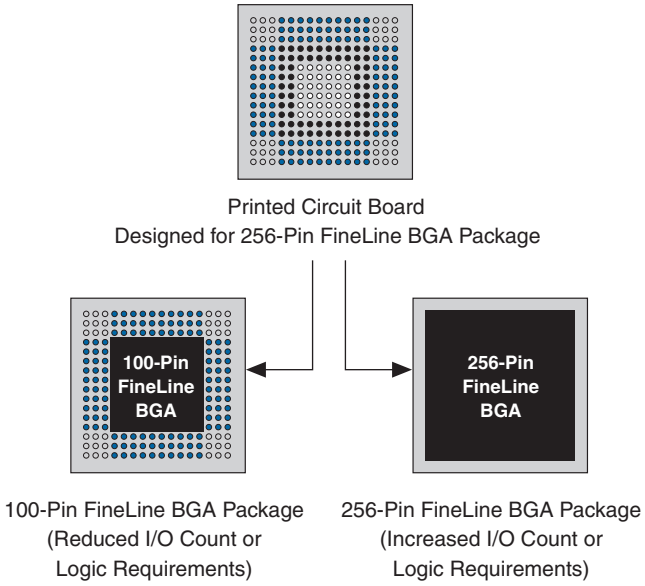


Table 6 lists the 3.3-V FLEX 6000 devices with the SameFrame pin-out feature.

Table 6. 3.3-V FLEX 6000 Devices with SameFrame Pin-Outs

Device	100-Pin FineLine BGA	256-Pin FineLine BGA
EPF6016A	v	v
EPF6024A		v

Output Configuration

This section discusses slew-rate control, the MultiVolt I/O interface, power sequencing, and hot-socketing for FLEX 6000 devices.

Slew-Rate Control

The output buffer in each IOE has an adjustable output slew-rate that can be configured for low-noise or high-speed performance. A slower slew-rate reduces system noise and adds a maximum delay of 6.8 ns. The fast slew-rate should be used for speed-critical outputs in systems that are adequately protected against noise. Designers can specify the slew-rate on a pin-by-pin basis during design entry or assign a default slew rate to all pins on a device-wide basis. The slew-rate setting affects only the falling edge of the output.

MultiVolt I/O Interface

The FLEX 6000 device architecture supports the MultiVolt I/O interface feature, which allows FLEX 6000 devices to interface with systems of differing supply voltages. The EPF6016 device can be set for 3.3-V or 5.0-V I/O pin operation. This device has one set of V_{CC} pins for internal operation and input buffers (VCCINT), and another set for output drivers (VCCIO).

The VCCINT pins on 5.0-V FLEX 6000 devices must always be connected to a 5.0-V power supply. With a 5.0-V V_{CCINT} level, input voltages are at TTL levels and are therefore compatible with 3.3-V and 5.0-V inputs.

The VCCIO pins on 5.0-V FLEX 6000 devices can be connected to either a 3.3-V or 5.0-V power supply, depending on the output requirements. When the VCCIO pins are connected to a 5.0-V power supply, the output levels are compatible with 5.0-V systems. When the VCCIO pins are connected to a 3.3-V power supply, the output high is 3.3 V and is therefore compatible with 3.3-V or 5.0-V systems. Devices operating with V_{CCIO} levels lower than 4.75 V incur a nominally greater timing delay of t_{OD2} instead of t_{OD1}.

On 3.3-V FLEX 6000 devices, the VCCINT pins must be connected to a 3.3-V power supply. Additionally, 3.3-V FLEX 6000A devices can interface with 2.5-V, 3.3-V, or 5.0-V systems when the VCCIO pins are tied to 2.5 V. The output can drive 2.5-V systems, and the inputs can be driven by 2.5-V, 3.3-V, or 5.0-V systems. When the VCCIO pins are tied to 3.3 V, the output can drive 3.3-V or 5.0-V systems. MultiVolt I/Os are not supported on 100-pin TQFP or 100-pin FineLine BGA packages.

Table 7 describes FLEX 6000 MultiVolt I/O support.

Table 7. FLEX 6000 MultiVolt I/O Support

V_{CCINT} (V)	V_{CCIO} (V)	Input Signal (V)			Output Signal (V)		
		2.5	3.3	5.0	2.5	3.3	5.0
3.3	2.5	v	v	v	v		
3.3	3.3	v	v	v	v *(1)*	v	v
5.0	3.3		v	v		v	v
5.0	5.0		v	v			v

Note:

(1) When V_{CCIO} = 3.3 V, a FLEX 6000 device can drive a 2.5-V device that has 3.3-V tolerant inputs.

The instruction register length for FLEX 6000 devices is three bits. Table 9 shows the boundary-scan register length for FLEX 6000 devices.

Table 9. FLEX 6000 Device Boundary-Scan Register Length

Device	Boundary-Scan Register Length
EPF6010A	522
EPF6016	621
EPF6016A	522
EPF6024A	666

FLEX 6000 devices include a weak pull-up on JTAG pins.

f See *Application Note 39 (IEEE 1149.1 (JTAG) Boundary-Scan Testing in Altera Devices)* for more information.

Figure 16 shows the timing requirements for the JTAG signals.

Figure 16. JTAG Waveforms

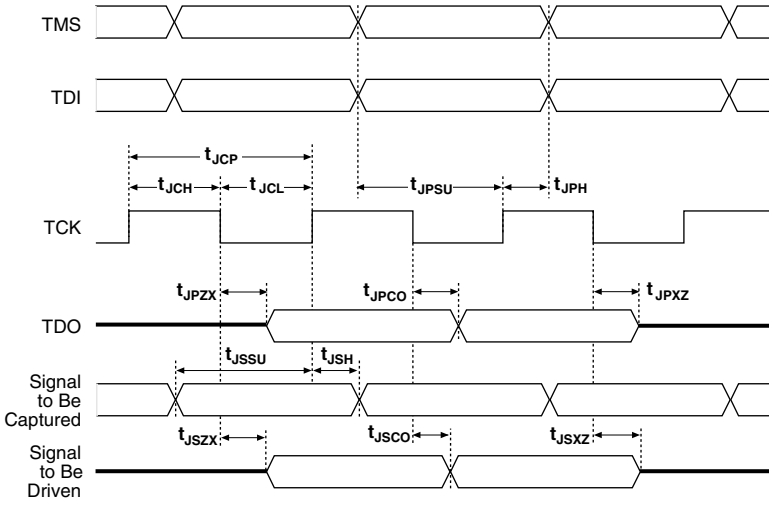


Table 10 shows the JTAG timing parameters and values for FLEX 6000 devices.

Table 13. FLEX 6000 5.0-V Device DC Operating Conditions *Notes (5), (6)*

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{IH}	High-level input voltage		2.0		V_{CCINT} + 0.5	V
V_{IL}	Low-level input voltage		–0.5		0.8	V
V_{OH}	5.0-V high-level TTL output voltage	I_{OH} = –8 mA DC, V_{CCIO} = 4.75 V *(7)*	2.4			V
	3.3-V high-level TTL output voltage	I_{OH} = –8 mA DC, V_{CCIO} = 3.00 V *(7)*	2.4			V
	3.3-V high-level CMOS output voltage	I_{OH} = –0.1 mA DC, V_{CCIO} = 3.00 V *(7)*	V_{CCIO} – 0.2			V
V_{OL}	5.0-V low-level TTL output voltage	I_{OL} = 8 mA DC, V_{CCIO} = 4.75 V *(8)*			0.45	V
	3.3-V low-level TTL output voltage	I_{OL} = 8 mA DC, V_{CCIO} = 3.00 V *(8)*			0.45	V
	3.3-V low-level CMOS output voltage	I_{OL} = 0.1 mA DC, V_{CCIO} = 3.00 V *(8)*			0.2	V
I_I	Input pin leakage current	V_I = V_{CC} or ground *(8)*	–10		10	µA
I_{OZ}	Tri-stated I/O pin leakage current	V_O = V_{CC} or ground *(8)*	–40		40	µA
I_{CC0}	V_{CC} supply current (standby)	V_I = ground, no load		0.5	5	mA

Table 14. FLEX 6000 5.0-V Device Capacitance *Note (9)*

Symbol	Parameter	Conditions	Min	Max	Unit
C_{IN}	Input capacitance for I/O pin	V_{IN} = 0 V, f = 1.0 MHz		8	pF
C_{INCLK}	Input capacitance for dedicated input	V_{IN} = 0 V, f = 1.0 MHz		12	pF
C_{OUT}	Output capacitance	V_{OUT} = 0 V, f = 1.0 MHz		8	pF

Notes to tables:

(1) See the *Operating Requirements for Altera Devices Data Sheet*.
(2) Minimum DC input is –0.5 V. During transitions, the inputs may undershoot to –2.0 V or overshoot to 7.0 V for input currents less than 100 mA and periods shorter than 20 ns.
(3) Numbers in parentheses are for industrial-temperature-range devices.
(4) Maximum V_{CC} rise time to 100 ms. V_{CC} must rise monotonically.
(5) Typical values are for T_A = 25° C and V_{CC} = 5.0 V.
(6) These values are specified under the FLEX 6000 Recommended Operating Conditions shown in Table 12 on page 31.
(7) The I_{OH} parameter refers to high-level TTL or CMOS output current.
(8) The I_{OL} parameter refers to low-level TTL, PCI, or CMOS output current. This parameter applies to open-drain pins as well as output pins.
(9) Capacitance is sample-tested only.

Table 15. FLEX 6000 3.3-V Device Absolute Maximum Ratings *Note (1)*

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	Supply voltage	With respect to ground *(2)*	–0.5	4.6	V
V_I	DC input voltage		–2.0	5.75	V
I_{OUT}	DC output current, per pin		–25	25	mA
T_{STG}	Storage temperature	No bias	–65	150	° C
T_{AMB}	Ambient temperature	Under bias	–65	135	° C
T_J	Junction temperature	PQFP, PLCC, and BGA packages		135	° C

Table 16. FLEX 6000 3.3-V Device Recommended Operating Conditions

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CCINT}	Supply voltage for internal logic and input buffers	*(3)*, *(4)*	3.00 (3.00)	3.60 (3.60)	V
V_{CCIO}	Supply voltage for output buffers, 3.3-V operation	*(3)*, *(4)*	3.00 (3.00)	3.60 (3.60)	V
	Supply voltage for output buffers, 2.5-V operation	*(3)*, *(4)*	2.30 (2.30)	2.70 (2.70)	V
V_I	Input voltage		–0.5	5.75	V
V_O	Output voltage		0	V_{CCIO}	V
T_J	Operating temperature	For commercial use	0	85	° C
		For industrial use	–40	100	° C
t_R	Input rise time			40	ns
t_F	Input fall time			40	ns

Table 17. FLEX 6000 3.3-V Device DC Operating Conditions *Notes (5), (6)*

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{IH}	High-level input voltage		1.7		5.75	V
V_{IL}	Low-level input voltage		–0.5		0.8	V
V_{OH}	3.3-V high-level TTL output voltage	I_{OH} = –8 mA DC, V_{CCIO} = 3.00 V *(7)*	2.4			V
	3.3-V high-level CMOS output voltage	I_{OH} = –0.1 mA DC, V_{CCIO} = 3.00 V *(7)*	V_{CCIO} – 0.2			V
	2.5-V high-level output voltage	I_{OH} = –100 µA DC, V_{CCIO} = 2.30 V *(7)*	2.1			V
		I_{OH} = –1 mA DC, V_{CCIO} = 2.30 V *(7)*	2.0			V
		I_{OH} = –2 mA DC, V_{CCIO} = 2.30 V *(7)*	1.7			V
V_{OL}	3.3-V low-level TTL output voltage	I_{OL} = 8 mA DC, V_{CCIO} = 3.00 V *(8)*			0.45	V
	3.3-V low-level CMOS output voltage	I_{OL} = 0.1 mA DC, V_{CCIO} = 3.00 V *(8)*			0.2	V
	2.5-V low-level output voltage	I_{OL} = 100 µA DC, V_{CCIO} = 2.30 V *(8)*			0.2	V
		I_{OL} = 1 mA DC, V_{CCIO} = 2.30 V *(8)*			0.4	V
		I_{OL} = 2 mA DC, V_{CCIO} = 2.30 V *(8)*			0.7	V
I_I	Input pin leakage current	V_I = 5.3 V to ground *(8)*	–10		10	µA
I_{OZ}	Tri-stated I/O pin leakage current	V_O = 5.3 V to ground *(8)*	–10		10	µA
I_{CC0}	V_{CC} supply current (standby)	V_I = ground, no load		0.5	5	mA

Table 18. FLEX 6000 3.3-V Device Capacitance *Note (9)*

Symbol	Parameter	Conditions	Min	Max	Unit
C_{IN}	Input capacitance for I/O pin	V_{IN} = 0 V, f = 1.0 MHz		8	pF
C_{INCLK}	Input capacitance for dedicated input	V_{IN} = 0 V, f = 1.0 MHz		12	pF
C_{OUT}	Output capacitance	V_{OUT} = 0 V, f = 1.0 MHz		8	pF

Notes to tables:

(1) See the *Operating Requirements for Altera Devices Data Sheet*.
(2) The minimum DC input voltage is –0.5 V. During transitions, the inputs may undershoot to –2.0 V or overshoot to 5.75 V for input currents less than 100 mA and periods shorter than 20 ns.
(3) Numbers in parentheses are for industrial-temperature-range devices.
(4) Maximum V_{CC} rise time is 100 ms. V_{CC} must rise monotonically.
(5) Typical values are for T_A = 25° C and V_{CC} = 3.3 V.
(6) These values are specified under Table 16 on page 33.
(7) The I_{OH} parameter refers to high-level TTL or CMOS output current.
(8) The I_{OL} parameter refers to low-level TTL, PCI, or CMOS output current. This parameter applies to open-drain pins as well as output pins.
(9) Capacitance is sample-tested only.

Tables 19 through 21 describe the FLEX 6000 internal timing microparameters, which are expressed as worst-case values. Using hand calculations, these parameters can be used to estimate design performance. However, before committing designs to silicon, actual worst-case performance should be modeled using timing simulation and timing analysis. Tables 22 and 23 describe FLEX 6000 external timing parameters.

Table 19. LE Timing Microparameters *Note (1)*

Symbol	Parameter	Conditions
$t_{REG\_TO\_REG}$	LUT delay for LE register feedback in carry chain	
$t_{CASC\_TO\_REG}$	Cascade-in to register delay	
$t_{CARRY\_TO\_REG}$	Carry-in to register delay	
$t_{DATA\_TO\_REG}$	LE input to register delay	
$t_{CASC\_TO\_OUT}$	Cascade-in to LE output delay	
$t_{CARRY\_TO\_OUT}$	Carry-in to LE output delay	
$t_{DATA\_TO\_OUT}$	LE input to LE output delay	
$t_{REG\_TO\_OUT}$	Register output to LE output delay	
t_{SU}	LE register setup time before clock; LE register recovery time after asynchronous clear	
t_{H}	LE register hold time after clock	
t_{CO}	LE register clock-to-output delay	
t_{CLR}	LE register clear delay	
t_{C}	LE register control signal delay	
t_{LD_CLR}	Synchronous load or clear delay in counter mode	
$t_{CARRY\_TO\_CARRY}$	Carry-in to carry-out delay	
$t_{REG\_TO\_CARRY}$	Register output to carry-out delay	
$t_{DATA\_TO\_CARRY}$	LE input to carry-out delay	
$t_{CARRY\_TO\_CASC}$	Carry-in to cascade-out delay	
$t_{CASC\_TO\_CASC}$	Cascade-in to cascade-out delay	
$t_{REG\_TO\_CASC}$	Register-out to cascade-out delay	
$t_{DATA\_TO\_CASC}$	LE input to cascade-out delay	
t_{CH}	LE register clock high time	
t_{CL}	LE register clock low time	

Table 26. Interconnect Timing Microparameters for EPF6010A & EPF6016A Devices

Parameter	Speed Grade						Unit
	-1		-2		-3		
	Min	Max	Min	Max	Min	Max	
t_{LOCAL}		0.7		0.7		1.0	ns
t_{ROW}		2.9		3.2		3.2	ns
t_{COL}		1.2		1.3		1.4	ns
t_{DIN_D}		5.4		5.7		6.4	ns
t_{DIN_C}		4.3		5.0		6.1	ns
$t_{LEGLOBAL}$		2.6		3.0		3.7	ns
$t_{LABCARRY}$		0.7		0.8		0.9	ns
$t_{LABCASC}$		1.3		1.4		1.8	ns

Table 27. External Reference Timing Parameters for EPF6010A & EPF6016A Devices

Parameter	Device	Speed Grade						Unit
		-1		-2		-3		
		Min	Max	Min	Max	Min	Max	
t_1	EPF6010A		37.6		43.6		53.7	ns
	EPF6016A		38.0		44.0		54.1	ns

Table 28. External Timing Parameters for EPF6010A & EPF6016A Devices

Parameter	Speed Grade						Unit
	-1		-2		-3		
	Min	Max	Min	Max	Min	Max	
t_{INSU}	2.1 *(1)*		2.4 *(1)*		3.3 *(1)*		ns
t_{INH}	0.2 *(2)*		0.3 *(2)*		0.1 *(2)*		ns
t_{OUTCO}	2.0	7.1	2.0	8.2	2.0	10.1	ns

Notes:
(1) Setup times are longer when the *Increase Input Delay* option is turned on. The setup time values are shown with the *Increase Input Delay* option turned off.
(2) Hold time is zero when the *Increase Input Delay* option is turned on.

Table 30. IOE Timing Microparameters for EPF6016 Devices

Parameter	Speed Grade				Unit
	-2		-3		
	Min	Max	Min	Max	
t_{OD3}		4.7		5.2	ns
t_{XZ}		2.3		2.8	ns
t_{ZX1}		2.3		2.8	ns
t_{ZX2}		4.6		5.1	ns
t_{ZX3}		4.7		5.2	ns
t_{IOE}		0.5		0.6	ns
t_{IN}		3.3		4.0	ns
t_{IN_DELAY}		4.6		5.6	ns

Table 31. Interconnect Timing Microparameters for EPF6016 Devices

Parameter	Speed Grade				Unit
	-2		-3		
	Min	Max	Min	Max	
t_{LOCAL}		0.8		1.0	ns
t_{ROW}		2.9		3.3	ns
t_{COL}		2.3		2.5	ns
t_{DIN_D}		4.9		6.0	ns
t_{DIN_C}		4.8		6.0	ns
$t_{LEGLOBAL}$		3.1		3.9	ns
$t_{LABCARRY}$		0.4		0.5	ns
$t_{LABCASC}$		0.8		1.0	ns

Table 32. External Reference Timing Parameters for EPF6016 Devices

Parameter	Speed Grade				Unit
	-2		-3		
	Min	Max	Min	Max	
t_1		53.0		65.0	ns
t_{DRR}		16.0		20.0	ns

Table 33. External Timing Parameters for EPF6016 Devices

Parameter	Speed Grade				Unit
	-2		-3		
	Min	Max	Min	Max	
t_{INSU}	3.2		4.1		ns
t_{INH}	0.0		0.0		ns
t_{OUTCO}	2.0	7.9	2.0	9.9	ns

Tables 34 through 38 show the timing information for EPF6024A devices.

Table 34. LE Timing Microparameters for EPF6024A Devices

Parameter	Speed Grade						Unit
	-1		-2		-3		
	Min	Max	Min	Max	Min	Max	
$t_{REG\_TO\_REG}$		1.2		1.3		1.6	ns
$t_{CASC\_TO\_REG}$		0.7		0.8		1.0	ns
$t_{CARRY\_TO\_REG}$		1.6		1.8		2.2	ns
$t_{DATA\_TO\_REG}$		1.3		1.4		1.7	ns
$t_{CASC\_TO\_OUT}$		1.2		1.3		1.6	ns
$t_{CARRY\_TO\_OUT}$		2.0		2.2		2.6	ns
$t_{DATA\_TO\_OUT}$		1.8		2.1		2.6	ns
$t_{REG\_TO\_OUT}$		0.3		0.3		0.4	ns
t_{SU}	0.9		1.0		1.2		ns
t_{H}	1.3		1.4		1.7		ns
t_{CO}		0.2		0.3		0.3	ns
t_{CLR}		0.3		0.3		0.4	ns
t_{C}		1.9		2.1		2.5	ns
t_{LD_CLR}		1.9		2.1		2.5	ns
$t_{CARRY\_TO\_CARRY}$		0.2		0.2		0.3	ns
$t_{REG\_TO\_CARRY}$		1.4		1.6		1.9	ns
$t_{DATA\_TO\_CARRY}$		1.3		1.4		1.7	ns
$t_{CARRY\_TO\_CASC}$		1.1		1.2		1.4	ns
$t_{CASC\_TO\_CASC}$		0.7		0.8		1.0	ns
$t_{REG\_TO\_CASC}$		1.4		1.6		1.9	ns
$t_{DATA\_TO\_CASC}$		1.0		1.1		1.3	ns
t_{CH}	2.5		3.0		3.5		ns
t_{CL}	2.5		3.0		3.5		ns

Operating Modes

The FLEX 6000 architecture uses SRAM configuration elements that require configuration data to be loaded every time the circuit powers up. This process of physically loading the SRAM data into a FLEX 6000 device is known as configuration. During initialization—a process that occurs immediately after configuration—the device resets registers, enables I/O pins, and begins to operate as a logic device. The I/O pins are tri-stated during power-up, and before and during configuration. The configuration and initialization processes of a device are referred to as *command mode*; normal device operation is called *user mode*.

SRAM configuration elements allow FLEX 6000 devices to be reconfigured in-circuit by loading new configuration data into the device. Real-time reconfiguration is performed by forcing the device into command mode with a device pin, loading different configuration data, reinitializing the device, and resuming user-mode operation. The entire reconfiguration process requires less than 100 ms and is used to dynamically reconfigure an entire system. Also, in-field system upgrades can be performed by distributing new configuration files.

Configuration Schemes

The configuration data for a FLEX 6000 device can be loaded with one of three configuration schemes, which is chosen on the basis of the target application. An EPC1 or EPC1441 configuration device or intelligent controller can be used to control the configuration of a FLEX 6000 device, allowing automatic configuration on system power-up.

Multiple FLEX 6000 devices can be configured in any of the three configuration schemes by connecting the configuration enable input (nCE) and configuration enable output (nCEO) pins on each device.

Table 40 shows the data sources for each configuration scheme.

Table 40. Configuration Schemes

Configuration Scheme	Data Source
Configuration device	EPC1 or EPC1441 configuration device
Passive serial (PS)	BitBlaster™, ByteBlasterMV™, or MasterBlaster™ download cables, or serial data source
Passive serial asynchronous (PSA)	BitBlaster, ByteBlasterMV, or MasterBlaster download cables, or serial data source